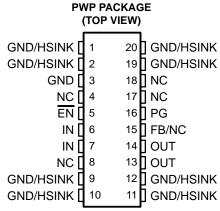
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- Controlled Baseline
 - One Assembly/Test Site, One Fabrication Site
- Extended Temperature Performance of –40°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product Change Notification
- Qualification Pedigree[†]
- 1 A Low-Dropout Voltage Regulator
- Available in 1.5-V, 1.8-V, 2.5-V, 2.7-V, 2.8-V, 3.0-V, 3.3-V, 5.0-V Fixed Output and Adjustable Versions
- Dropout Voltage Down to 230 mV at 1 A (TPS76850)
- Ultralow 85 μA Typical Quiescent Current
- † Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- Fast Transient Response
- 2% Tolerance Over Specified Conditions for Fixed-Output Versions
- Open Drain Power Good (See TPS767xx for Power-On Reset With 200-ms Delay Option)
- 20-Pin TSSOP (PWP)PowerPAD™ Package
- Thermal Shutdown Protection



NC - No internal connection

description

This device is designed to have a fast transient response and be stable with $10-\mu F$ low ESR capacitors. This combination provides high performance at a reasonable cost.

Because the PMOS device behaves as a low-value resistor, the dropout voltage is very low (typically 230 mV at an output current of 1 A for the TPS76850) and is directly proportional to the output current. Additionally, since the PMOS pass element is a voltage-driven device, the quiescent current is very low and independent of output loading (typically 85 μ A over the full range of output current, 0 mA to 1 A). These two key specifications yield a significant improvement in operating life for battery-powered systems. This LDO family also features a sleep mode; applying a TTL high signal to $\overline{\text{EN}}$ (enable) shuts down the regulator, reducing the quiescent current to less than 1 μ A at $T_{\text{L}} = 25^{\circ}\text{C}$.

Power good (PG) is an active high output, which can be used to implement a power-on reset or a low-battery indicator.

The TPS768xx is offered in 1.5-V, 1.8-V, 2.5-V, 2.7-V, 2.8-V, 3.0-V, 3.3-V, and 5.0-V fixed-voltage versions and in an adjustable version (programmable over the range of 1.2 V to 5.5 V). Output voltage tolerance is specified as a maximum of 2% over line, load, and temperature ranges. The TPS768xx family is available in a 20-pin PWP package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.

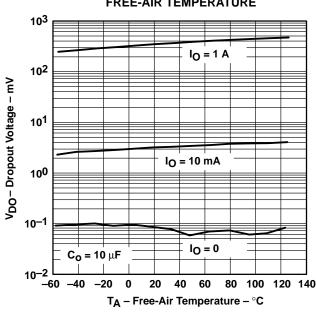


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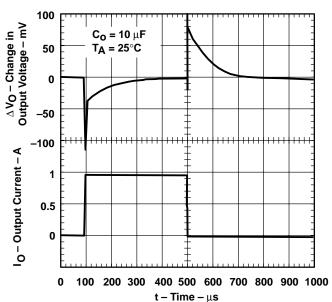
description (continued)

TPS76833 DROPOUT VOLTAGE





LOAD TRANSIENT RESPONSE



ORDERING INFORMATION

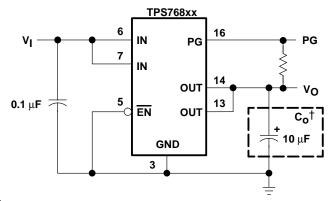
TJ	OUTPUT VOLTAGE (V) TYP	PACKAGE		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
	5.0			TPS76850QPWPREP	76850EP	
	3.3	TSSOP - PWP		TPS76833QPWPREP	76833EP	
	3.0		Tape and reel	TPS76830QPWPREP†	76830EP [†]	
	2.8			TPS76828QPWPREP†	76828EP [†]	
-40°C to 125°C	2.7			TPS76827QPWPREP†	76827EP†	
40 0 10 123 0	2.5			TPS76825QPWPREP	76825EP	
	1.8			TPS76818QPWPREP	76818EP	
	1.5			TPS76815QPWPREP	76815EP	
	Adjustable 1.2 V to 5.5 V			TPS76801QPWPREP	76801EP	

[†] This device is Product Preview.

The TPS76801 is programmable using an external resistor divider (see application information). The PWP package is available taped and reeled. Note R suffix to the device type (e.g., TPS76801QPWPREP).



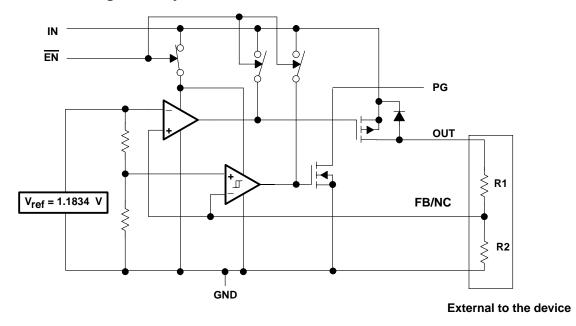
description (continued)



[†] See application information section for capacitor selection details.

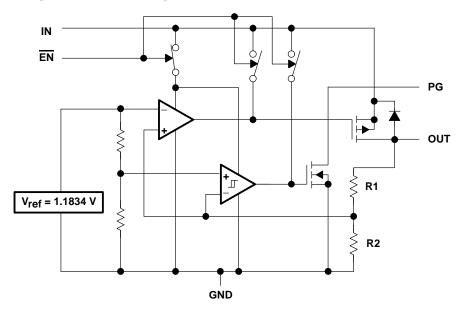
Figure 1. Typical Application Configuration (For Fixed Output Options)

functional block diagram—adjustable version



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functional block diagram—fixed-voltage version



Terminal Functions

PWP Package

TERMINAL			
NAME	NO.	1/0	DESCRIPTION
GND/HSINK	1		Ground/heatsink
GND/HSINK	2		Ground/heatsink
GND	3		LDO ground
NC	4		No connect
EN	5	- 1	Enable input
IN	6	I	Input
IN	7	- 1	Input
NC	8		No connect
GND/HSINK	9		Ground/heatsink
GND/HSINK	10		Ground/heatsink
GND/HSINK	11		Ground/heatsink
GND/HSINK	12		Ground/heatsink
OUT	13	0	Regulated output voltage
OUT	14	0	Regulated output voltage
FB/NC	15	I	Feedback input voltage for adjustable device (no connect for fixed options)
PG	16	0	PG output
NC	17		No connect
NC	18		No connect
GND/HSINK	19		Ground/heatsink
GND/HSINK	20		Ground/heatsink



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Input voltage range [‡] , V _I	0.3 V to 13.5 V
Voltage range at EN	$-0.3 \text{ V to V}_{\text{I}} + 0.3 \text{ V}$
Maximum PG voltage	16.5 V
Peak output current	Internally limited
Continuous total power dissipation	. See dissipation rating tables
Output voltage, V _O (OUT, FB)	7 V
Operating virtual junction temperature range, T _J	–40°C to 125°C
Storage temperature range, T _{stq}	65°C to 150°C
ESD rating, HBM	2 kV

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE - FREE-AIR TEMPERATURES

PACKAGE	AIR FLOW (CFM)	T _A < 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
514/56	0	2.9 W	23.5 mW/°C	1.9 W	1.5 W
PWP§	300	4.3 W	34.6 mW/°C	2.8 W	2.2 W
Para	0	3 W	23.8 mW/°C	1.9 W	1.5 W
PWP¶	300	7.2 W	57.9 mW/°C	4.6 W	3.8 W

[§] This parameter is measured with the recommended copper heat sink pattern on a 1-layer PCB, 5-in × 5-in PCB, 1 oz. copper, 2-in × 2-in coverage (4 in²).

recommended operating conditions

	MIN	MAX	UNIT
Input voltage, VI#	2.7	10	V
Output voltage range, VO	1.2	5.5	V
Output current, IO (see Note 1)	0	1.0	Α
Operating virtual junction temperature, T _J (see Note 1)	-40	125	°C

[#] To calculate the minimum input voltage for your maximum output current, use the following equation: V_I(min) = V_O(max) + V_{DO}(max load).

NOTE 1: Continuous current and operating junction temperature are limited by internal protection circuitry, but it is not recommended that the device operate under conditions beyond those specified in this table for extended periods of time.



[‡] All voltage values are with respect to network terminal ground.

[¶] This parameter is measured with the recommended copper heat sink pattern on a 8-layer PCB, 1.5-in × 2-in PCB, 1 oz. copper with layers 1, 2, 4, 5, 7, and 8 at 5% coverage (0.9 in²) and layers 3 and 6 at 100% coverage (6 in²). For more information, refer to TI technical brief SLMA002.

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electrical characteristics over recommended operating free-air temperature range, $V_I = V_{O(tvp)} + 1 V$, $I_O = 1 mA$, $\overline{EN} = 0 V$, $C_O = 10 \mu F$ (unless otherwise noted)

PARAMETEI	२	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
		$5.5 \text{ V} \ge \text{V}_{\text{O}} \ge 1.5 \text{ V},$	T _J = 25°C		٧o		
	TPS76801	$5.5 \text{ V} \ge \text{V}_{\text{O}} \ge 1.5 \text{ V},$	$T_J = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$	0.98V _O		1.02V _O	
		T _J = 25°C,	2.7 V < V _{IN} < 10 V		1.5		
	TPS76815	$T_J = -40^{\circ}\text{C to } 125^{\circ}\text{C},$	2.7 V < V _{IN} < 10 V	1.470		1.530	
	TD070040	T _J = 25°C,	2.8 V < V _{IN} < 10 V		1.8		
	TPS76818	$T_J = -40^{\circ}\text{C to } 125^{\circ}\text{C},$	2.8 V < V _{IN} < 10 V	1.764		1.836	
	TD070005	$T_J = 25^{\circ}C$,	3.5 V < V _{IN} < 10 V		2.5		
	TPS76825	$T_J = -40^{\circ}C$ to 125°C,	3.5 V < V _{IN} < 10 V	2.450		2.550	
Output voltage (10 μA to 1 A load)	TD070007	T _J = 25°C,	3.7 V < V _{IN} < 10 V		2.7		.,
(see Note 2)	TPS76827	$T_J = -40^{\circ}C$ to $125^{\circ}C$,	$3.7 \text{ V} < \text{V}_{1N} < 10 \text{ V}$	2.646		2.754	V
,	TPS76828	$T_J = 25^{\circ}C$,	3.8 V < V _{IN} < 10 V		2.8		
	17570020	$T_J = -40^{\circ}C$ to $125^{\circ}C$,	$3.8 \text{ V} < \text{V}_{1N} < 10 \text{ V}$	2.744		2.856	
	TPS76830	$T_J = 25^{\circ}C$,	4 V < V _{IN} < 10 V		3.0		
	17576630	$T_J = -40^{\circ}C$ to $125^{\circ}C$,	4 V < V _{IN} < 10 V	2.940		3.060	
	TDCZCGGG		4.3 V < V _{IN} < 10 V		3.3		
	TPS76833	$T_J = -40^{\circ}C$ to $125^{\circ}C$,	4.3 V < V _{IN} < 10 V	3.234		3.366	
	TPS76850	$T_J = 25^{\circ}C$,	6 V < V _{IN} < 10 V		5.0		
	17576650	$T_J = -40^{\circ}C$ to $125^{\circ}C$,	6 V < V _{IN} < 10 V	4.900		5.100	
Quiescent current (GND current)		$10 \mu A < I_O < 1 A$,	T _J = 25°C		85		
EN = 0V, (see Note 2)		I _O = 1 A,	$T_J = -40^{\circ}C$ to $125^{\circ}C$			125	μΑ
Output voltage line regulation (Δ V (see Notes 2 and 3)	′O/VO)	$V_{O} + 1 V < V_{I} \le 10 V$	T _J = 25°C		0.01		%/V
Load regulation					3		mV
Output noise voltage (TPS76818)	1	BW = 200 Hz to 100 k	•		55		μVrms
- Catpat Holoc Voltage (11 07 00 10)	'	$C_0 = 10 \mu F, I_C = 1 A,$	T _J = 25°C				μνιιιο
Output current limit		V _O = 0 V			1.7	2	Α
Thermal shutdown junction temper	erature				150		°C
Standby current		EN = V _I , 2.7 V < V _I < 10 V	$T_J = 25^{\circ}C$,		1		μΑ
		EN = V _I , 2.7 V < V _I < 10 V	$T_J = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			10	μΑ
FB input current	TPS76801	FB = 1.5 V			2		nA
High level enable input voltage				1.7			V
Low level enable input voltage						0.9	V
Power supply ripple rejection (see	e Note 2)	f = 1 KHz, T _J = 25°C	$C_0 = 10 \mu F$,		60		dB

NOTES: 2. Minimum IN operating voltage is 2.7 V or V_{O(typ)} + 1 V, whichever is greater. Maximum IN voltage 10 V. 3. If V_O ≤ 1.8 V then V_{Imax} = 10 V, V_{Imin} = 2.7 V:

Line Reg. (mV) =
$$(\%/V) \times \frac{V_O(V_{Imax} - 2.7 \text{ V})}{100} \times 1000$$

If $V_O \ge 2.5 \text{ V}$ then V_{lmax} = 10 V, V_{lmin} = V_O + 1 V:

Line Reg. (mV) =
$$(\%/V) \times \frac{V_O(V_{Imax} - (V_O + 1 V))}{100} \times 1000$$



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electrical characteristics over recommended operating free-air temperature range, $V_I = V_{O(tvp)} + 1 \text{ V}$, $I_O = 1 \text{ mA}$, $\overline{EN} = 0 \text{ V}$, $C_O = 10 \text{ }\mu\text{F}$ (unless otherwise noted) (continued)

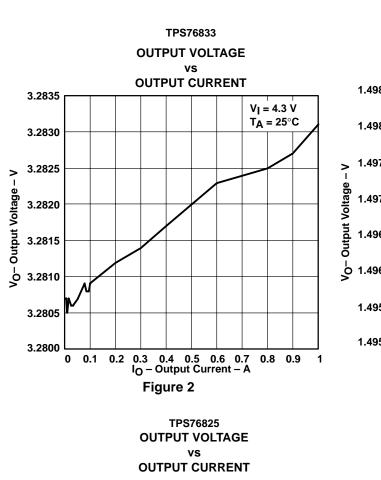
	PARAMETER		TEST (CONDITIONS	MIN	TYP	MAX	UNIT
Minimum input voltage for valid PG		I _O (PG) = 300 μA			1.1		V	
	Trip threshold voltage		VO decreasing		92		98	%Vo
PG	Hysteresis voltage		Measured at VO			0.5		%Vo
	Output low voltage		V _I = 2.7 V,	$I_{O(PG)} = 1 \text{ mA}$		0.15	0.4	V
	Leakage current		V _(PG) = 5 V				1	μΑ
			EN = 0 V		-1	0	1	•
input c	current (EN)		EN = V _I		-1		1	μΑ
		TPS76828	I _O = 1 A,	T _J = 25°C		500		
			I _O = 1 A,	$T_J = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			825	
			I _O = 1 A,	T _J = 25°C		450		
	Dropout voltage	TPS76830	I _O = 1 A,	$T_J = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			675	
(see Note 4)	TD070000	I _O = 1 A,	T _J = 25°C		350		mV	
	TPS76833	I _O = 1 A,	$T_J = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$			575		
		TD070050	I _O = 1 A,	T _J = 25°C		230		
		TPS76850	I _O = 1 A,	$T_J = -40^{\circ}\text{C to } 125^{\circ}\text{C}$			380	

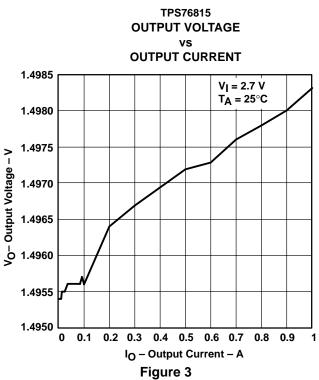
NOTE 4: IN voltage equals V_O(typ) – 100 mV; TPS76801 output voltage set to 3.3 V nominal with external resistor divider. TPS76815, TPS76818, TPS76825, and TPS76827 dropout voltage limited by input voltage range limitations (i.e., TPS76830 input voltage needs to drop to 2.9 V for purpose of this test).

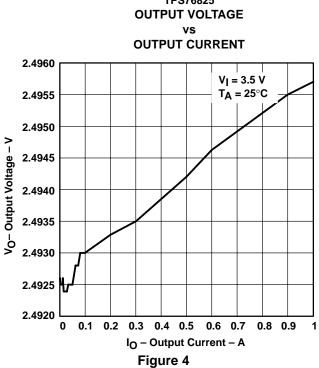
TYPICAL CHARACTERISTICS

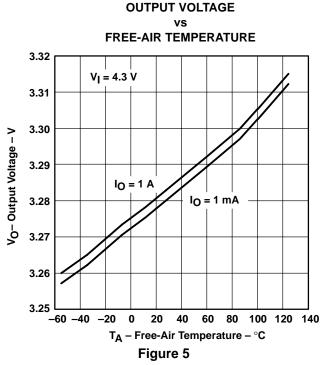
Table of Graphs

			FIGURE
	Outrot wells as	vs Output current	2, 3, 4
VO	Output voltage	vs Free-air temperature	5, 6, 7
	Ground current	vs Free-air temperature	8, 9
	Power supply ripple rejection	vs Frequency	10
	Output spectral noise density	vs Frequency	11
	Input voltage (min)	vs Output voltage	12
Z _O	Output impedance	vs Frequency	13
V_{DO}	Dropout voltage	vs Free-air temperature	14
	Line transient response		15, 17
	Load transient response		16, 18
VO	Output voltage	vs Time	19
	Dropout voltage	vs Input voltage	20
	Equivalent series resistance (ESR)	vs Output current	22 – 25





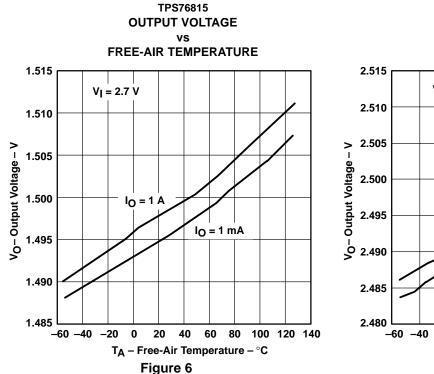


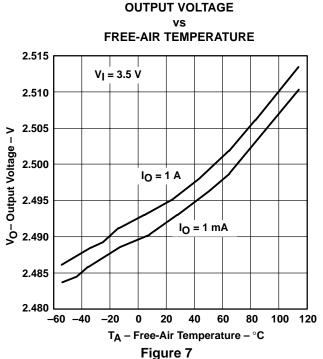


TPS76833



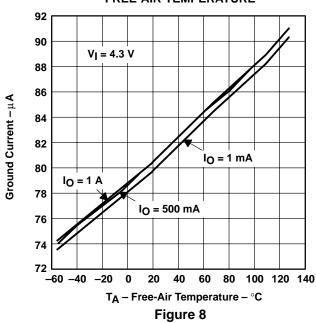
TYPICAL CHARACTERISTICS





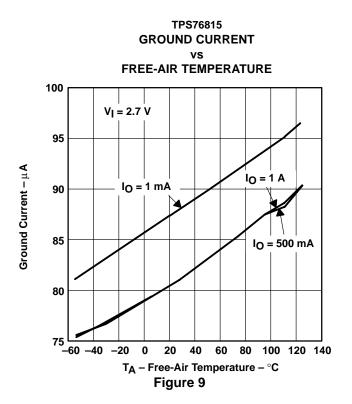
TPS76825

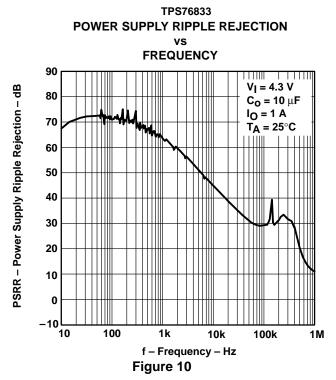
TPS76833 GROUND CURRENT vs FREE-AIR TEMPERATURE



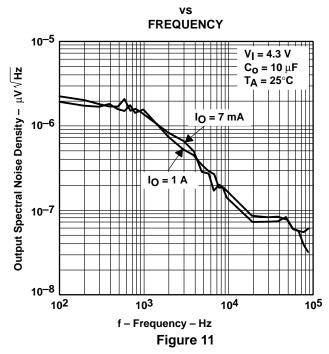


TYPICAL CHARACTERISTICS





TPS76833 OUTPUT SPECTRAL NOISE DENSITY





INPUT VOLTAGE (MIN)

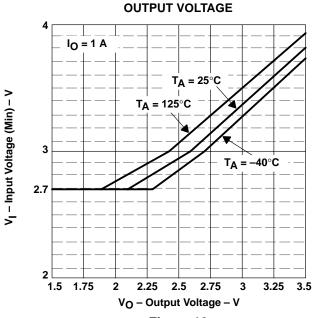


Figure 12

TPS76833 OUTPUT IMPEDANCE FREQUENCY

 $V_{|} = 4.3 V$ C_O = 10 μF TA = 25°C $\mathbf{Z_0}$ – Output Impedance – Ω 102 103 104 105 106 f - Frequency - kHz Figure 13

TPS76833 DROPOUT VOLTAGE vs

FREE-AIR TEMPERATURE

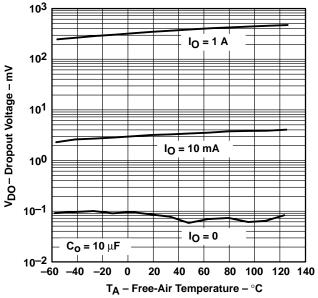
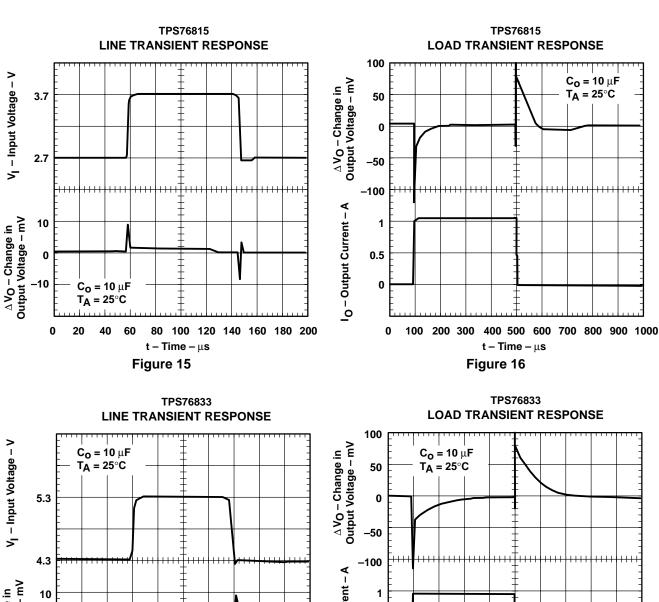


Figure 14



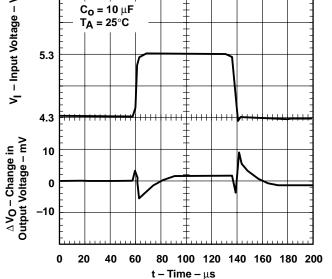


Figure 17

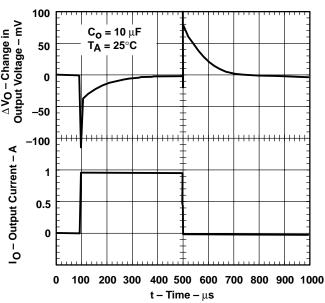


Figure 18

TYPICAL CHARACTERISTICS

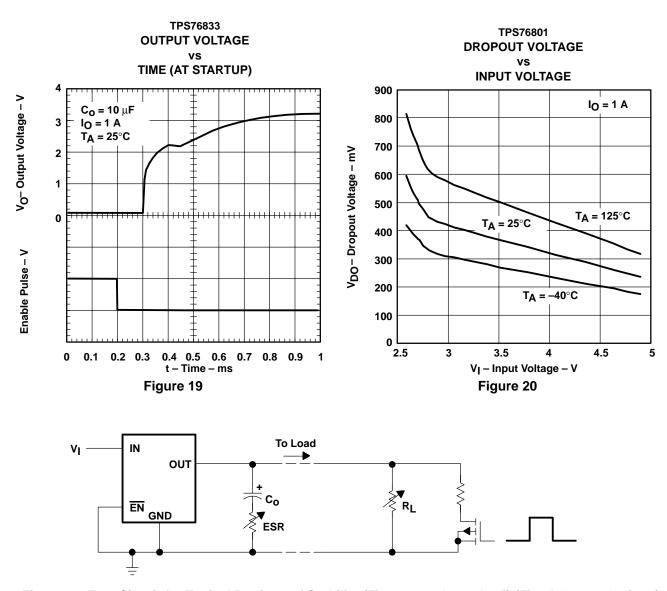


Figure 21. Test Circuit for Typical Regions of Stability (Figures 22 through 25) (Fixed Output Options)

TYPICAL REGION OF STABILITY **EQUIVALENT SERIES RESISTANCE**[†] vs **OUTPUT CURRENT** Region of Instability

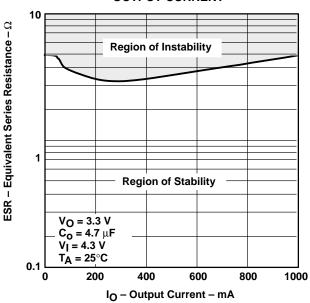
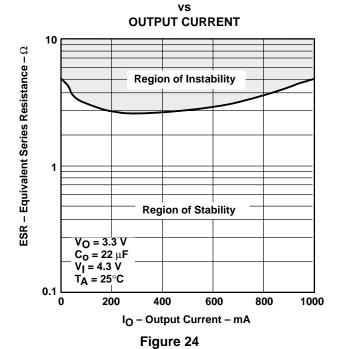
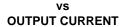


Figure 22

TYPICAL REGION OF STABILITY **EQUIVALENT SERIES RESISTANCE**[†]



TYPICAL REGION OF STABILITY EQUIVALENT SERIES RESISTANCE[†]



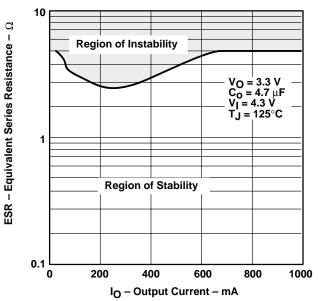


Figure 23

TYPICAL REGION OF STABILITY EQUIVALENT SERIES RESISTANCE[†]

vs **OUTPUT CURRENT**

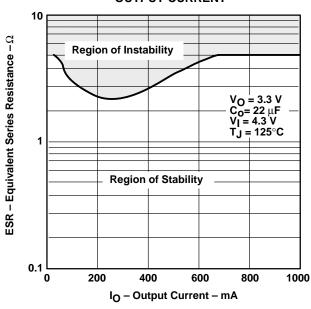


Figure 25

[†] Equivalent series resistance (ESR) refers to the total series resistance, including the ESR of the capacitor, any series resistance added externally, and PWB trace resistance to Co.



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APPLICATION INFORMATION

The TPS768xx family includes eight fixed-output voltage regulators (1.5 V, 1.8 V, 2.5 V, 2.7 V, 2.8 V, 3.0 V, 3.3 V, and 5.0 V), and offers an adjustable device, the TPS76801 (adjustable from 1.2 V to 5.5 V).

device operation

The TPS768xx features very low quiescent current, which remains virtually constant even with varying loads. Conventional LDO regulators use a pnp pass element, the base current of which is directly proportional to the load current through the regulator ($I_B = I_C/\beta$). The TPS768xx uses a PMOS transistor to pass current; because the gate of the PMOS is voltage driven, operating current is low and invariable over the full load range.

Another pitfall associated with the pnp-pass element is its tendency to saturate when the device goes into dropout. The resulting drop in β forces an increase in I_B to maintain the load. During power up, this translates to large start-up currents. Systems with limited supply current may fail to start up. In battery-powered systems, it means rapid battery discharge when the voltage decays below the minimum required for regulation. The TPS768xx quiescent current remains low even when the regulator drops out, eliminating both problems.

The TPS768xx family also features a shutdown mode that places the output in the high-impedance state (essentially equal to the feedback-divider resistance) and reduces quiescent current to 2 μ A. If the shutdown feature is not used, $\overline{\text{EN}}$ should be tied to ground.

minimum load requirements

The TPS768xx family is stable even at zero load; no minimum load is required for operation.

FB - pin connection (adjustable version only)

The FB pin is an input pin to sense the output voltage and close the loop for the adjustable option. The output voltage is sensed through a resistor divider network to close the loop as shown in Figure 27. Normally, this connection should be as short as possible; however, the connection can be made near a critical circuit to improve performance at that point. Internally, FB connects to a high-impedance wide-bandwidth amplifier and noise pickup feeds through to the regulator output. Routing the FB connection to minimize/avoid noise pickup is essential.

external capacitor requirements

An input capacitor is not usually required; however, a ceramic bypass capacitor (0.047 μ F or larger) improves load transient response and noise rejection if the TPS768xx is located more than a few inches from the power supply. A higher-capacitance electrolytic capacitor may be necessary if large (hundreds of milliamps) load transients with fast rise times are anticipated.

Like all low dropout regulators, the TPS768xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance value is 10 μF and the ESR (equivalent series resistance) must be between 50 m Ω and 1.5 Ω . Capacitor values 10 μF or larger are acceptable, provided the ESR is less than 1.5 Ω . Solid tantalum electrolytic, aluminum electrolytic, and multilayer ceramic capacitors are all suitable, provided they meet the requirements described above. Most of the commercially available 10 μF surface-mount ceramic capacitors, including devices from Sprague and Kemet, meet the ESR requirements stated above.



APPLICATION INFORMATION

external capacitor requirements (continued)

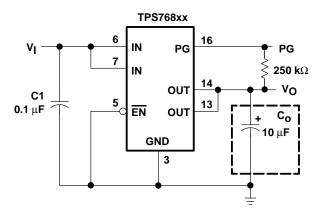


Figure 26. Typical Application Circuit (Fixed Versions)

programming the TPS76801 adjustable LDO regulator

The output voltage of the TPS76801 adjustable regulator is programmed using an external resistor divider as shown in Figure 27. The output voltage is calculated using:

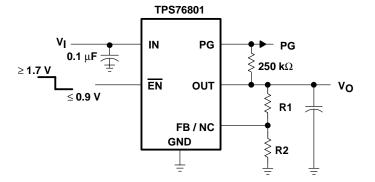
$$V_{O} = V_{ref} \times \left(1 + \frac{R1}{R2}\right) \tag{1}$$

Where:

 $V_{ref} = 1.1834 \text{ V typ (the internal reference voltage)}$

Resistors R1 and R2 should be chosen for approximately 50- μ A divider current. Lower value resistors can be used but offer no inherent advantage and waste more power. Higher values should be avoided as leakage currents at FB increase the output voltage error. The recommended design procedure is to choose R2 = $30.1~k\Omega$ to set the divider current at $50~\mu$ A and then calculate R1 using:

$$R1 = \left(\frac{V_{O}}{V_{ref}} - 1\right) \times R2 \tag{2}$$



OUTPUT VOLTAGE PROGRAMMING GUIDE

OUTPUT VOLTAGE	R1	R2	UNIT
2.5 V	33.2	30.1	kΩ
3.3 V	53.6	30.1	kΩ
3.6 V	61.9	30.1	kΩ
4.75 V	90.8	30.1	kΩ

Figure 27. TPS76801 Adjustable LDO Regulator Programming



APPLICATION INFORMATION

power-good indicator

The TPS768xx features a power-good (PG) output that can be used to monitor the status of the regulator. The internal comparator monitors the output voltage: when the output drops to between 92% and 98% of its nominal regulated value, the PG output transistor turns on, taking the signal low. The open-drain output requires a pullup resistor. If not used, it can be left floating. PG can be used to drive power-on reset circuitry or used as a low-battery indicator. PG does not assert itself when the regulated output voltage falls out of the specified 2% tolerance, but instead reports an output voltage low, relative to its nominal regulated value.

regulator protection

The TPS768xx PMOS-pass transistor has a built-in back diode that conducts reverse currents when the input voltage drops below the output voltage (e.g., during power down). Current is conducted from the output to the input and is not internally limited. When extended reverse voltage is anticipated, external limiting may be appropriate.

The TPS768xx also features internal current limiting and thermal protection. During normal operation, the TPS768xx limits output current to approximately 1.7 A. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 150°C(typ), thermal-protection circuitry shuts it down. Once the device has cooled below 130°C(typ), regulator operation resumes.

power dissipation and junction temperature

Specified regulator operation is assured to a junction temperature of 125° C; the maximum junction temperature should be restricted to 125° C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_{D} , which must be less than or equal to $P_{D(max)}$.

The maximum-power-dissipation limit is determined using the following equation:

$$P_{D(max)} = \frac{T_J max - T_A}{R_{\theta,JA}}$$

Where:

T_.Imax is the maximum allowable junction temperature.

 $R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package, i.e., 172°C/W for the 8-terminal SOIC and 32.6°C/W for the 20-terminal PWP with no airflow.

T_A is the ambient temperature.

The regulator dissipation is calculated using:

$$P_D = (V_I - V_O) \times I_O$$

Power dissipation resulting from quiescent current is negligible. Excessive power dissipation will trigger the thermal protection circuit.

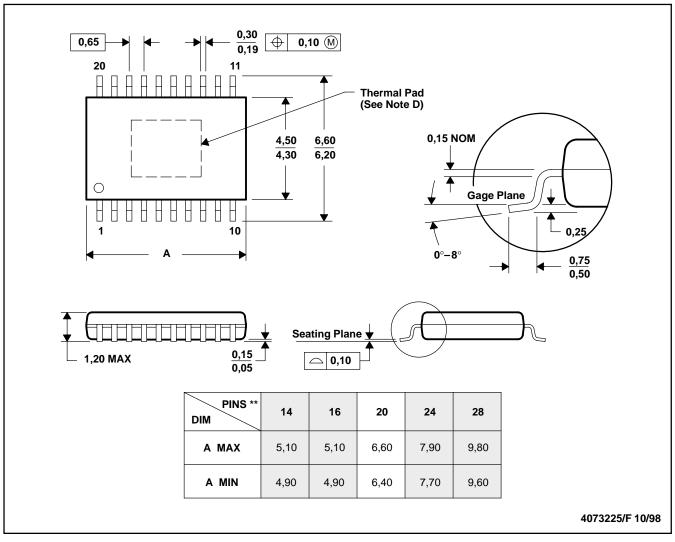


MECHANICAL DATA

PWP (R-PDSO-G**)

PowerPAD™ PLASTIC SMALL-OUTLINE

20 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusions.
- D. The package thermal performance may be enhanced by bonding the thermal pad to an external thermal plane. This pad is electrically and thermally connected to the backside of the die and possibly selected leads.
- E. Falls within JEDEC MO-153

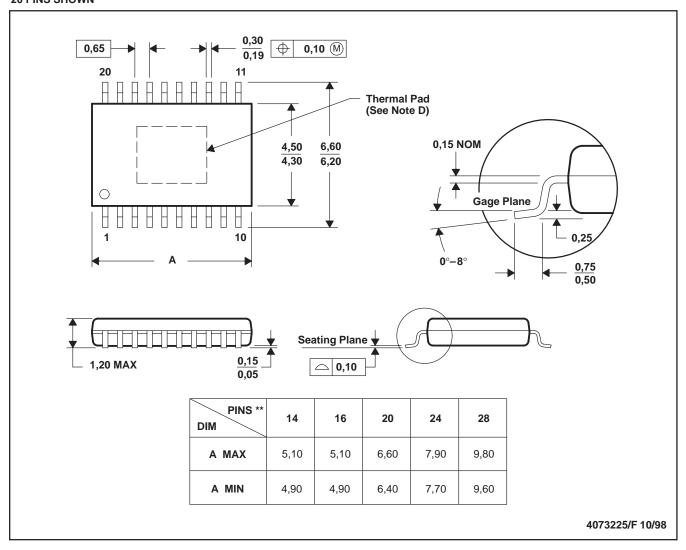
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PWP (R-PDSO-G**)

20 PINS SHOWN

PowerPAD™ PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

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